



2-Channel, 1:3, USB 2.0 and MHL MUX/DeMUX

Description

The DIODES PI3USB3031 device is a 2-channel, 1:3 multiplexer that includes a high-speed Mobile High Definition Link (MHL), Mobility Display Port (MyDP) switch, and USB 2.0 High-Speed (480 Mbps) switches in the same package. These configurations allow the system designer to save board space and eliminate multiple connectors buy using a common USB or Mico-USB connector for MHL/MyDP signals and two sets of USB data. The MHL/MyDP path supports the latest MHL Rev. 3.0 specification.

The PI3USB3031 has a VCC range of 1.8V to 5.5V and supports overvoltage tolerance (OVT) feature, which allows the I/O pins to withstand overvoltage conditions (up to 5.5 V). The power-off protection feature forces all I/O pins to be in high impedance mode when power is not present, allowing full isolation of the signals lines under such condition without excessive leakage current. The select pins of PI3USB3031 are compatible with 1.8V control voltage, allowing them to be directly interfaced with the General Purpose I/O (GPIO) from a mobile processor with out needing additional voltage level shifting circuitry.

The PI3USB3031 comes with a small 12-pin VQFN package with only 1.8mm x 1.8mm and QFN package with only 1.6mm x 1.6mm in size, which makes it a perfect candidate to be used in mobile applications.

Block Diagram



Features

- Wide VCC Range: 1.8V to 5.5V •
- Mobile High-Definition Link (MHL) or Mobility Display Port (MyDP) Switch:
 - Bandwidth (-3dB): 6.5GHz
 - R_{ON} (Typical): 5.5Ω
 - C_{ON} (Typical): 1.3pF
- USB Switches (2 Sets):
- Bandwidth (-3dB): 6.5GHz
- R_{ON} (Typical): 4.5Ω
- C_{ON} (Typical): 1pF
- ٠ Current Consumption: 28 µA (Typical)
- IOFF Protection Prevents Current Leakage in Powered-Down ٠ State (VCC = 0V)
- 1.8V Compatible Control Inputs (SEL) ٠
- Overvoltage Tolerance (OVT) on All I/O Pins Up to 5V Without • External Components
- ٠ ESD Protection : 2kV(HBM), 1kV(CDM)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control • (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/
- Packaging (Pb-free & Green):
 - ¹² 12-Pin, 1.8mm x 1.8mm, 0.4mm pitch (WQFN)
 - 12-Pin, 1.6mm x 1.6mm, 0.4mm pitch (X2-QFN)

Application(s)

- PC Motherboards
- Notebooks
- Servers
- Smartphones
- Portable Instrumentation
- Digital Cameras USB 2.0 MHL

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.





Pin Configuration



Pin Description

Pin#	Pin Name	Туре	Description
1	SEL0	Ι	Digital Control Input 1
2	SEL1	Ι	Digital Control Input 2
3	USB1+	I/O	Differential Signal Path 1
4	USB1-	I/O	Differential Signal Path 1
5	USB2+	I/O	Differential Signal Path 2
6	USB2-	I/O	Differential Signal Path 2
7	MHL+	I/O	Differential Signal Path 3
8	MHL-	I/O	Differential Signal Path 3
9	GND	GND	Ground
10	D-	I/O	Common Differential Signal Path
11	D+	I/O	Common Differential Signal Path
12	VCC	POWER	Power Supply

Truth Table

SEL1	SEL0	Source Connected To Common Pin
Low	Low	USB1+/- connect to D+/-
Low	High	USB2+/- connect to D+/-
High	Low	MHL+/- connect to D+/-
High	High	USB and MHL switches in High-Z





Maximum Ratings

(Above which useful life may be impaired. For user guidelines, not tested.)

Storage Temperature65°C to +150°C
Ambient Temperature with Power Applied40°C to +125°C
Supply Voltage V _{CC} –0.3V to +6.0V
DC Input Voltage for Control (SEL0 & SEL1)0.3V to +6.0V
DC Input Voltage for Switch I/O (Dx/USBx/MHLx)0.3V to +5.0V
Continuous DC Output Current (USB & MHL) ±15mA
ESD (HBM)±2kV
ESD (CDM)±1kV

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions

Symbol	Parameter	Min.	Тур.	Max.	Units
V _{CC}	Operating Voltage	1.8	3.3	5.5	V
V _{I/O (USB)} V _{I/O (MHL)}	Analog Voltage	0		3.6	V
V _{SEL}	Select Input Voltage (SEL0, SEL1)	0		V _{CC}	V
T _A	Operating Temperature	-40	25	85	°C

DC Electrical Characteristics

Symbol	Parameter	Test Conditions	TA	Min.	Тур.	Max.	Units	
MHL SWIT	MHL SWITCH							
R _{ON}	On-Resistance	V _{CC} = 2.5V, V _{I/O} = 1.5V, I _{ON} = -8mA, Test Circuit 1	25°C		5.5	7	Ω	
ΔR_{ON}	On-resistance matching be- tween channels	$V_{CC} = 2.5V, V_{I/O} = 1.5V, I_{ON} = -8mA$	25°C		0.1		Ω	
R _{ONF}	On-Resistance Flatness	$V_{CC} = 2.5V, V_{I/O} = 1.5V$ to 3.3V, $I_{ON} = -8mA$	25°C		1		Ω	
I _{OZ}	Off Leakage Current	$V_{CC} = 4.3V, \text{ Switch OFF.}$ $V_{MHL+/MHL-} = 1.5V \text{ to } 3.3V;$ $V_{D+/D-} = 0V$	25°C	-2		2	μΑ	
I _{ON}	ON Leakage Current	$V_{CC} = 4.3V, Power OFF.$ $V_{MHL+/MHL-} = 1.5V \text{ to } 3.3V;$ $V_{D+/D-} = NC$	-40°C to 85°C	-2		2	μΑ	
I _{OFF}	Power Off leakage Current	$V_{CC} = 0V$, Power OFF. $V_{MHL+/}$ MHL- = 1.5V to 3.3V; $V_{D+/D-} =$ NC	-40°C to 85°C	-10		10	μΑ	





Symbol	Parameter	Test Conditions	TA	Min.	Тур.	Max.	Units
USB SWITC	H (USB1 & USB2)	· · · ·		·			
R _{ON}	On-Resistance	V _{CC} = 2.5V, V _{I/O} = 0.4V, I _{ON} = -8mA, Test Circuit 1	25°C		4.5	6	Ω
ΔR_{ON}	On-resistance matching be- tween channels	$V_{CC} = 2.5V, V_{I/O} = 0.4V, I_{ON} = -8mA$	25°C		0.1		Ω
R _{ONF}	On-Resistance Flatness	$\label{eq:VCC} \begin{split} V_{CC} &= 2.5 \text{V}, V_{I/O} = 0 \text{V to } 0.4 \text{V}, \\ I_{ON} &= -8 \text{mA} \end{split}$	25°C		1		Ω
I _{OZ}	Off Leakage Current	V_{CC} = 4.3V, Switch OFF. $V_{USB+/USB-}$ = 0V to 0.4V; $V_{D+/D-}$ = 0V	25°C	-2		2	μΑ
I _{ON}	ON Leakage Current	V_{CC} = 4.3V, Switch ON. $V_{USBHL+/USB-}$ = 0V to 0.4V; $V_{D+/D-}$ = NC	25°C	-2		2	μΑ
I _{OFF}	Power Off leakage Current	$V_{CC} = 0V$, Power ON or OFF. $V_{USBHL+/USB-} = 0V$ to 0.4V; $V_{D+/D-} = NC$	25°C	-10		10	μΑ
Select INPUT	TS (SEL0, SEL1)						
V _{IH}	Input Logic High	$V_{CC} = 2.5 V$ to $4.3 V$	25°C	1.3			V
V _{IL}	Input Logic Low	$V_{CC} = 2.5 V$ to $4.3 V$	25°C	0		0.6	V
I _{IN}	Input Leakage Current	V_{CC} = 2.5V, $V_{I/O}$ = 0V to 0.4V, I_{ON} = -8mA	25°C	-10		10	μΑ

Dynamic Characteristics

+3.3V Supply (V_{CC} = $3.3V \pm 10\%$) Symbol Parameter **Test Conditions** Min. Max. Units TA Typ. $R_L = 50\Omega$, $C_L = 5pF$, $V_{CC} =$ Propagation delay Time 2.5V to 4.3V, $V_{I/O(USB)} = 0.4V$, 25°C 50 ps t_{pd} $V_{I/O(MHL)} = 3.3V$ Switching time between USB/ $R_L = 50\Omega, C_L = 5pF, V_{CC} =$ MHL channels in active 2.5V to 4.3V, $V_{I/O(USB)} = 0.4V$, 25°C 400 t_{switch} ns modes $V_{I/O(MHL)} = 3.3V$ $R_L = 50\Omega, C_L = 5pF, V_{CC} =$ Turn-On Time 2.5V to 4.3V, $V_{I/O(USB)} = 0.4V$, 25°C 100 ton μs $V_{I/O(MHL)} = 3.3V$ $R_L = 50\Omega$, $C_L = 5pF$, $V_{CC} =$ Turn-Off Time 2.5V to 4.3V, $V_{I/O(USB)} = 0.4V$, 100 25°C tOFF μs $V_{I/O(MHL)} = 3.3V$ MHL Channels On Capaci- $V_{CC} = 3.3V, V_{I/O} = 0V \text{ or } 3.3V,$ 25°C 1.3 C_{ON(MHL)} pF tance f = 240 MHz, Switch ON $V_{CC} = 3.3V, V_{I/O} = 0V \text{ or } 3.3V,$ USB Channel On Capacitance 25°C pF 1 C_{ON(USB)} f = 240 MHz, Switch ON





Symbol	Parameter	Test Conditions	TA	Min.	Тур.	Max.	Units
C _{OFF(MHL)}	MHL Channels Off Capaci- tance	$V_{CC} = 3.3V$, $V_{I/O} = 0V$ or 3.3V, f = 240MHz, Switch OFF	25°C		1.3		pF
C _{OFF(USB)}	USB Channel Off Capacitance	$\label{eq:VCC} \begin{split} V_{CC} &= 3.3 V, V_{I/O} = 0 V \text{ or } 3.3 V, \\ f &= 240 \text{ MHz}, \text{Switch OFF} \end{split}$	25°C		1		pF
CI	Digital Input Capacitance	$V_{CC} = 3.3V, V_{I/O} = 0V \text{ or } 2V$	25°C		2.2		pF
O _{ISO(MHL)}	MHL path Off Isolations	$V_S = -10$ dBm, $V_{DC_BIAS} =$ 2.4V, RT = 50 Ω , f = 240MHz, Switch OFF	25°C		-38		dB
O _{ISO(USB)} USB path Off Isolations		$V_S = -10 dBm$, $V_{DC_BIAS} =$ 0.2V, RT = 50 Ω , f = 240MHz, Switch OFF	25°C		-38		dB
X _{TALK(MHL)}	MHL Channel Crosstalk	$V_S = -10 dBm$, $V_{DC_BIAS} =$ 2.4V, RT = 50 Ω , f = 240MHz, Switch ON	25°C		-65		dB
X _{TALK} (USB)	USB Channel Crosstalk	$V_S = -10 dBm$, $V_{DC_BIAS} =$ 0.2V, RT = 50 Ω , f = 240MHz, Switch ON	25°C		-45		dB
f _{3dB(MHL)}	-3dB Bandwidth	V_{CC} = 2.5V to 4.3V, R_L = 50 Ω , Switch ON	25°C		6.5		GHz
f _{3dB(USB)} -3dB Bandwidth		V_{CC} = 2.5V to 4.3V, R_L = 50 Ω , Switch ON	25°C		6.5		GHz
SUPPLY							
I _{CC} Power Supply Current		$V_{CC} = 4.3V$, $V_{IN} = V_{CC}$ or GND, $V_{I/O} = 0V$, Switch ON or OFF	25°C		28	40	μΑ





Test Circuits and Timing Diagrams



Figure 1. On Resistance



Figure 2. OFF Leakage Current IOZ



Figure 3. Differential OFF Isolation (OISO)







Figure 4. Crosstalk



Figure 5. Differential Bandwidth

Part Marking







Packaging Mechanical

12-WQFN (ZN)







12-X2QFN (XUA)



For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

Ordering Information

Ordering Code	Package Code	Package Description
PI3USB3031ZNEX	ZN	12-Pin, W-QFN1818-12 (WQFN)
PI3USB3031XUAEX	XUA	12-Pin, X2-QFN1616-12 (X2QFN)

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. E = Pb-free and Green

5. X suffix = Tape/Reel





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